SCBS479 - MARCH 1993 - REVISED MAY 1994

 BiCMOS Design Significantly Reduces I_{CCZ} ESD Protection Exceeds 2000 V Per 	DW OR N PACKAGE (TOP VIEW)
MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)	1 0E
 High-Impedance State During Power Up and Power Down 	2Y4 3 18 1Y1 1A2 4 17 2A4 2Y3 5 16 1Y2
 Open-Collector Outputs Drive Bus Lines or Buffer-Memory Address Registers 	1A3 [6 15] 2A3 2Y2 [7 14] 1Y3
 Package Options Include Plastic Small-Outline (DW) Packages and Standard Plastic and Ceramic 300-mil DIPs (N) 	1A4 [8 13] 2A2 2Y1 [9 12] 1Y4 GND [10 11] 2A1

description

This octal buffer and line driver is designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. The device provides complementary output-enable (OE and OE) inputs and noninverting outputs.

The SN64BCT757 is characterized for operation from -40°C to 85°C and 0°C to 70°C.

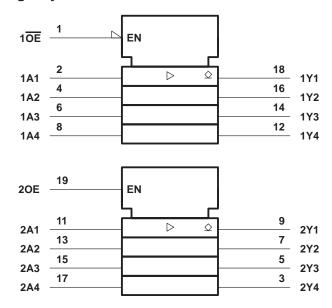
FUNCTION TABLES

INPU	JTS	OUTPUT
10E	1A	1Y
Н	Χ	Н
L	L	L
L	Н	Н

INP	JTS	OUTPUT
20E	2A	2Y
L	Χ	Н
Н	L	L
Н	Н	Н

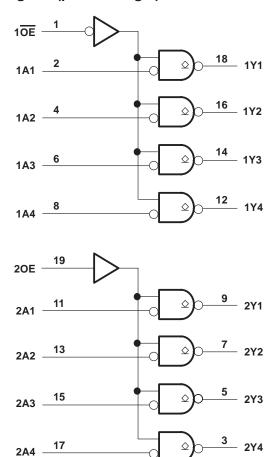
SCBS479 - MARCH 1993 - REVISED MAY 1994

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}	\dots -0.5 V to 7 V
Input voltage range, V _I (see Note 1)	\dots -0.5 V to 7 V
Voltage range applied to any output in the disabled or power-off state, VO	\ldots –0.5 V to 5.5 V
Voltage range applied to any output in the high state, VO	\dots -0.5 V to V _{CC}
Input clamp current, I _{IK} (V _I < 0)	–30 mA
Current into any output in the low state, IO	128 mA
Operating free-air temperature range	40°C to 85°C
Storage temperature range	-65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input negative-voltage ratings may be exceeded if the input clamp-current ratings are observed.



SCBS479 - MARCH 1993 - REVISED MAY 1994

recommended operating conditions (see Note 2)

		MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	V
VIH	High-level input voltage	2			V
V _{IL}	Low-level input voltage			0.8	V
Vон	High-level output voltage			5.5	V
I _{IK}	Input clamp current			-18	mA
l _{OL}	Low-level output current			64	mA
Δt/ΔV _{CC}	Power-up ramp rate	2			μs/V
TA	Operating free-air temperature	-40		85	°C

NOTE 2: Unused or floating inputs must be held high or low.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TES	ST CONDITIONS		MIN	TYP [†]	MAX	UNIT
VIK	V _{CC} = 4.5 V,	I _I = -18 mA				-1.2	V
IOH	V _{CC} = 4.5 V,	V _{OH} = 5.5 V				0.1	mA
V _{OL}	V _{CC} = 4.5 V,	$I_{OL} = 64 \text{ mA}$			0.42	0.55	V
loz	$V_{CC} = 0$ to 2.3 V (power up),	$V_0 = 2.7 V$,	OE = 0.8 V or OE = 2 V			50	μΑ
loz	$V_{CC} = 1.8 \text{ V to 0 (power down)},$	$V_0 = 2.7 V$	OE = 0.8 V or OE = 2 V			50	μΑ
l _l	V _{CC} = 5.5 V,	$V_I = 7 V$				0.1	mA
lін	V _{CC} = 5.5 V,	V _I = 2.7 V				20	μΑ
Ι _{ΙL}	V _{CC} = 5.5 V,	V _I = 0.5 V				-1	mA
			Outputs high			34	
Icc	$V_{CC} = 5.5 V,$	Outputs open	Outputs low			77	mA
		OE and OE inactive				10	
C _i	V _{CC} = 5 V,	V _I = 2.5 V or 0.5	V		6	·	рF
Co	V _{CC} = 5 V,	V _O = 2.5 V or 0.5	5 V		4	·	pF

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

switching characteristics over recommended range of supply voltage, C_L = 50 pF (unless otherwise noted) (see Note 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)		CC = 5 V 4 = 25°C		T _A = -		T _A = to 70		UNIT	
	(INPOT)		MIN	TYP	MAX	MIN	MAX	MIN	MAX		
^t PLH	А	· ·	6.9	8.3	9.6	6.5	11.2	6.6	10.1	20	
tPHL	A	Ť	2.4	4.2	6	1.9	7	2	6.6	ns	
^t PLH	205	205	· ·	11	14.8	17.9	10.4	21.3	10.8	19.7	20
tpHL	20E	Ť	2.9	4.6	6.2	2.6	7.5	2.6	6.9	ns	
^t PLH	1 OE	·	11.4	13.9	16.1	8.9	19.9	10	18	ne	
t _{PHL}	IOE	ĭ	4.4	6.1	7.8	4	9.2	4	8.5	ns	

NOTE 3: Load circuits and voltage waveforms are shown in Section 1.



www.ti.com 30-Jul-2024

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN64BCT757DW	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	-40 to 85	6BCT757	
SN64BCT757DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	6BCT757	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 16-Apr-2024

TAPE AND REEL INFORMATION



TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN64BCT757DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

www.ti.com 16-Apr-2024



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN64BCT757DWR	SOIC	DW	20	2000	367.0	367.0	45.0



SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2024, Texas Instruments Incorporated